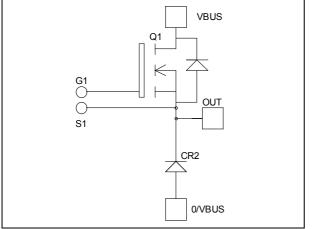
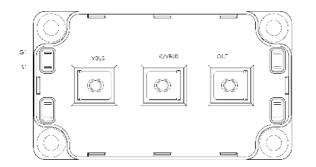


Buck chopper MOSFET Power Module

$V_{DSS} = 100V$ $R_{DSon} = 2.25m\Omega \text{ typ} @ \text{Tj} = 25^{\circ}\text{C}$ $I_D = 495\text{A} @ \text{Tc} = 25^{\circ}\text{C}$





Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Power MOS V[®] MOSFETs
 - · Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
 - Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V _{DSS}	Drain - Source Breakdown Voltage		100	V
т	Continuous Drain Current	$T_c = 25^{\circ}C$	495	
I _D		$T_c = 80^{\circ}C$	370	А
I _{DM}	Pulsed Drain current	1900		
V _{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		2.5	mΩ
PD	Maximum Power Dissipation $T_c = 25^{\circ}C$		1250	W
I _{AR}	Avalanche current (repetitive and non repetitive)		100	А
EAR	Repetitive Avalanche Energy		50	mJ
E _{AS}	Single Pulse Avalanche Energy	3000	111J	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
I _{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$ $T_j = 25^{\circ}C$			400	μA
		$V_{GS} = 0V, V_{DS} = 80V$ $T_j = 125^{\circ}C$			2000	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 200A$		2.25	2.5	mΩ
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 10 \text{mA}$	2		4	V
I _{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 V, V_{DS} = 0V$			±400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C _{iss}	Input Capacitance	$V_{GS} = 0V$		40		
C _{oss}	Output Capacitance	$V_{\rm DS} = 25 V$		15.7		nF
C _{rss}	Reverse Transfer Capacitance	f=1MHz		5.9		
Qg	Total gate Charge	$V_{GS} = 10V$		1360		
Q _{gs}	Gate – Source Charge	$V_{Bus} = 50V$		240		nC
Q_{gd}	Gate – Drain Charge	$I_{\rm D} = 400 {\rm A}$		720		
T _{d(on)}	Turn-on Delay Time	Inductive switching @ 125°C		160		
Tr	Rise Time	$V_{GS} = 15V$ $V_{Bus} = 66V$		240		n c
T _{d(off)}	Turn-off Delay Time	$I_{\rm D} = 400 \text{A}$		500		ns
$T_{\rm f}$	Fall Time	$R_G = 1.25\Omega$		160		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		2.2		mJ
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 400A, R_G = 1.25\Omega$		2.41		IIIJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		2.43		
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 400A, R_G = 1.25\Omega$		2.56		mJ

Chopper diode ratings and characteristics

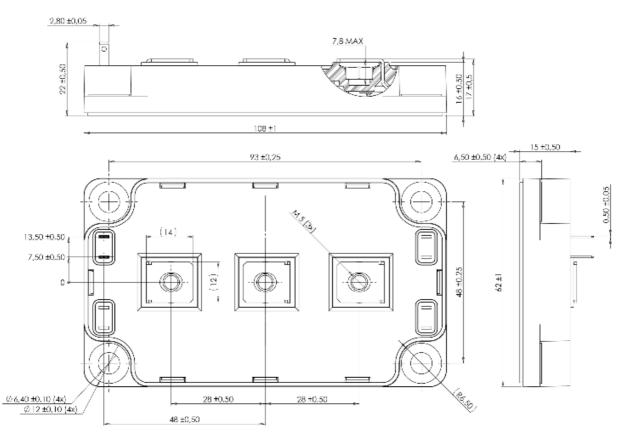
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			200			V
I _{RM}	Maximum Reverse Leakage Current	V _R =200V	$T_j = 25^{\circ}C$			750	μA
- Kivi			$T_{j} = 125^{\circ}C$			1000	per I
$I_{\rm F}$	DC Forward Current		$Tc = 80^{\circ}C$		400		А
	Diode Forward Voltage	$I_F = 400A$			1		v
V _F		$I_F = 800A$			1.4		
		$I_{\rm F} = 400 {\rm A}$	$T_{i} = 125^{\circ}C$		0.9		
t _{rr}	Reverse Recovery Time	1 400 4	$T_j = 25^{\circ}C$		60		ns
*11		$I_{\rm F} = 400 \text{A}$ $V_{\rm R} = 133 \text{V}$	$T_{j} = 125^{\circ}C$		110		110
Q _{rr}	Reverse Recovery Charge	$di/dt = 800 \text{A}/\mu \text{s}$	$T_j = 25^{\circ}C$		800		nC
Qrr	Reverse Recovery charge		$T_{j} = 125^{\circ}C$		3360		пс



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R _{thJC}	Junction to Case Thermal Resistance		Transistor			0.1	°C/W
R _{thJC}			Diode			0.14	
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T _J	Operating junction temperature range			-40		150	
T _{STG}	Storage Temperature Range			-40		125	°C
T _C	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	s M5	2		3.5	19.111
Wt	Package Weight					300	g

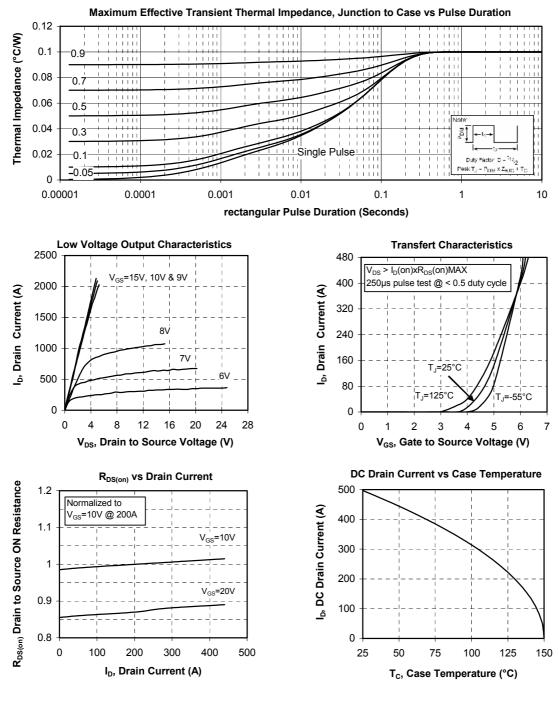
SP6 Package outline (dimensions in mm)



See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com



Typical Performance Curve

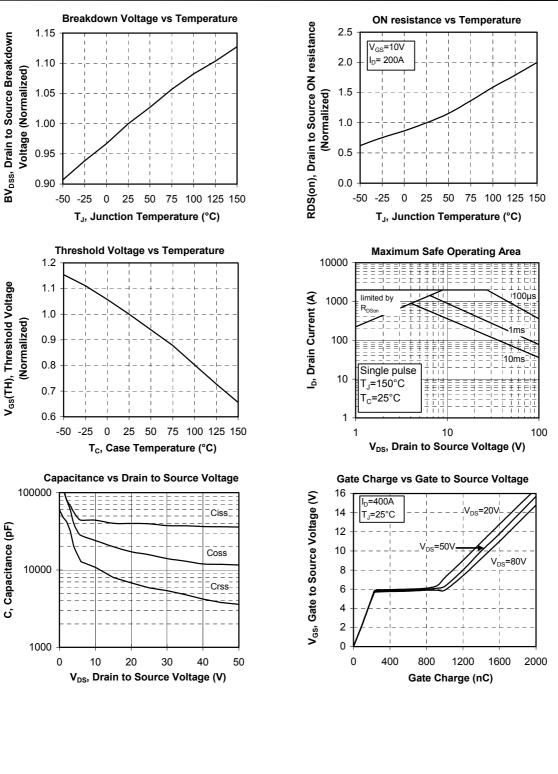


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C, Capacitance (pF)

APTM10SKM02G



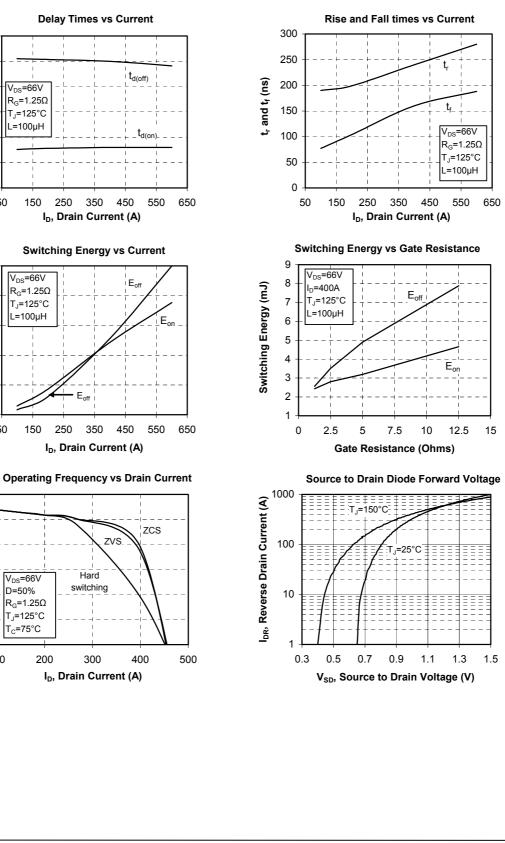


Frequency (kHz)

Eon and Eoff (mJ)

t_{d(on)} and t_{d(off)} (ns)

APTM10SKM02G





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